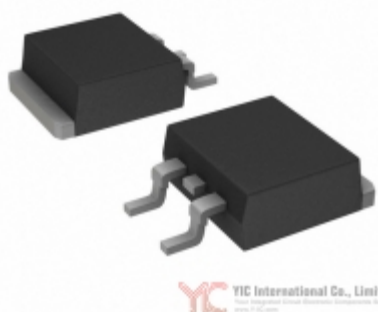




	<h2 style="color: #E67E22;">HGT1S7N60C3DS9A</h2>	
	<b>Hersteller-Teilenummer:</b>	<a href="#">HGT1S7N60C3DS9A</a>
	<b>Hersteller / Marke:</b>	<a href="#">AMI Semiconductor / ON Semiconductor</a>
	<b>Teil der Beschreibung:</b>	IGBT 600V 14A 60W TO263AB
<b>Datenblätter:</b>	 <a href="#">HGT1S7N60C3DS9A.pdf</a>	
<b>RoHs Status:</b>	Bleifrei / RoHS-konform	
<b>Lagerzustand:</b>	New original, 5562 pcs Stock Available.	
<b>Liefern von:</b>	Hong Kong	
<b>Versandweg:</b>	DHL/Fedex/TNT/UPS/EMS	
<p>Image may be representation. See specs for product details.</p>		

### Spezifikationen

Teilenummer	<a href="#">HGT1S7N60C3DS9A</a>
Hersteller	<a href="#">AMI Semiconductor / ON Semiconductor</a>
Beschreibung	IGBT 600V 14A 60W TO263AB
Kategorie	<a href="#">Diskrete Halbleiterprodukte &gt; Transistoren-IGBTs-</a>
Teilstatus	5562 pcs Stock
detaillierte Beschreibung	IGBT 600V 14A 60W Surface Mount TO-263AB
Serie	-
Eingabetyp	Standard
Betriebstemperatur	-
Befestigungsart	Surface Mount
Leistung - max	60W
Verpackung / Gehäuse	TO-263-3, D <sup>2</sup> Pak (2 Leads + Tab), TO-263AB
Supplier Device-Gehäuse	TO-263AB
Rückwärts-Erholzeit (Trr)	37ns
Strom - Kollektor (Ic) (max)	14A
Spannung - Kollektor-Emitter-Durchbruch (max)	600V
IGBT-Typ	-
VCE (on) (Max) @ Vge, Ic	2V @ 15V, 7A
Strom - Collector Pulsed (Icm)	56A
Schaltenergie	165µJ (on), 600µJ (off)
Gate-Ladung	23nC
Td (ein / aus) bei 25 ° C	-
Testbedingung	480V, 7A, 50 Ohm, 15V
Verpackung	Tape & Reel (TR)
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)

HGT1S7N60C3DS9A ist neu im Original, Suche HGT1S7N60C3DS9A Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie HGT1S7N60C3DS9A AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage HGT1S7N60C3DS9A: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <p><b>HGT1S7N60B3S</b> INTERSIL HGT1S7N60B3S INTERSIL</p>	 <p><b>HGT4E40N60B3S</b> Intersil Intersil TO-268</p>	 <p><b>HGT1S7N60C3DS</b> AMI Semiconductor / ON Semiconductor IGBT 600V 14A 60W TO263AB</p>	 <p><b>HGT1S7N60C3DS</b> Fairchild/ON Semiconductor IGBT 600V 14A 60W TO263AB</p>
 <p><b>HGT1S7N60C3DS9A</b> Fairchild/ON Semiconductor IGBT 600V 14A 60W TO263AB</p>	 <p><b>HGTD1N120BNS</b> FAIRCHILD HGTD1N120BNS FAIRCHILD</p>	 <p><b>HGTD1N120B</b> FAIRCHLD HGTD1N120B FAIRCHLD</p>	 <p><b>HGT1S7N60C3D</b> FAIRCHILD HGT1S7N60C3D FAIRCHILD</p>

### heiße Teile

Mehr

⚙ HGT1S14N41G3VL29A	➡ HGT1S14N41G3VLS9A	➡ HGT1S15N120C3ST	D HGT1S1N120CNDST	➡ HGT1S20N36G3VLS
⊖ HGT1S20N36G3VLSR4737	⚙ HGT1S20N60A4S9A	D HGT1S20N60A4S9A	➡ HGT1S20N60C3R	➡ HGT1S20N60C3RS
⚙ HGT1S2N120CN	⊖ HGT1S2N120CN	⚙ HGT1S3N60A4DS	➡ HGT1S3N60A4DS9A	➡ HGT1S3N60A4DS9A
D HGT1S3N60B3DS	⚙ HGT1S3N60C3DS9A	⊖ HGT1S7N60A4DS	⚙ HGT1S7N60A4DS	➡ HGT1S7N60A4DS.G7N60A4D
➡ HGT1S7N60A4DS9A	➡ HGT1S7N60A4S9A	⚙ HGT1S7N60B3	⊖ HGT1S7N60B3DS	➡ HGT1S7N60B3S
➡ HGT1S7N60C3DS9A	➡ HGTD1N120BNS9A	D HGTD1N120BNS9A	⚙ HGTG10N120BND	⊖ HGTG10N120BND
⚙ HGTG11N120CN	D HGTG11N120CN	➡ HGTG11N120CND	➡ HGTG11N120CND	➡ HGTG12N60A4
⊖ HGTG12N60A4	⚙ HGTG12N60A4D	➡ HGTG12N60A4D	➡ HGTG12N60B3D	➡ HGTG12N60C3D
⚙ HGTG12N60C3D	⊖ HGTG18N120BN	⚙ HGTG18N120BN	D HGTG18N120BND	➡ HGTG18N120BND
➡ HGTG20N120CND	⚙ HGTG20N120E2	⊖ HGTG20N50C1D	⚙ HGTG20N60	➡ HGTG20N60A4

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

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